

## Wireless charging for consumer

Introducing a new cost effective system solution to ensure excellent user experience



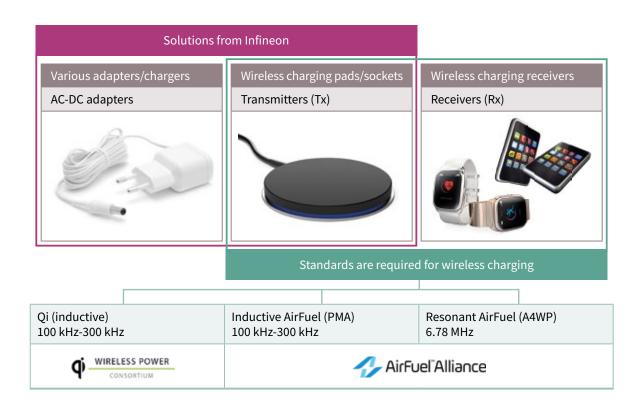
## Wireless charging for consumer applications

#### What is wireless charging?

Wireless charging uses electromagnetic fields to transfer power from a transmitter to a receiver application to charge the according battery. This erases the need of physical connectors and cables to transfer power – one of many benefits of this technology.

The wireless charging market is dominated by two standards: inductive (Qi) and resonant (resonant AirFuel). Infineon offers solutions for both standards and is an active member of the leading wireless charging alliances the Wireless Power Consortium (WPC) and AirFuel.





## Key enabling products for your transmitter and adapter solution:

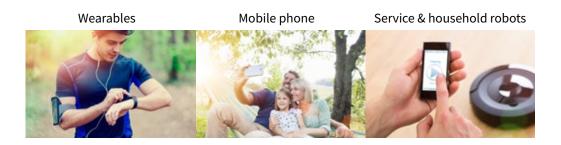
- > Low and mid voltage power MOSFETs OptiMOS™ and IR MOSFET™
- > Driver ICs EiceDRIVER™
- > Microcontrollers XMC™
- > High voltage power MOSFETs CoolMOS™ CE/P7
- > PWM/flyback controllers and integrated power stage ICs CoolSET™
- > Synchronous rectification ICs and MOSFETs OptiMOS™

## Choose Infineon to solve your application requirements:

- > High performance MOSFETs, ICs and MCU at optimum price/performance ratio thanks to cost-effective packages and leading, reliable and mature silicon technology
- > High power density in small designs: Enabling the lowest switching and conduction losses in smallest packages for MOSFETs and power stage
- > Smallest possible package size (2 x 2, 3 x 3 half-bridge) for low power MOSFETs 30 V-250 V
- > Highest efficiency: In hard switching topologies, enjoy low switching losses thanks to low input and output capacitances

Infineon is working on its own medium voltage GaN technology and will bring it to the market with a significant performance increase over silicon MOSFETs at the same level of reliability.

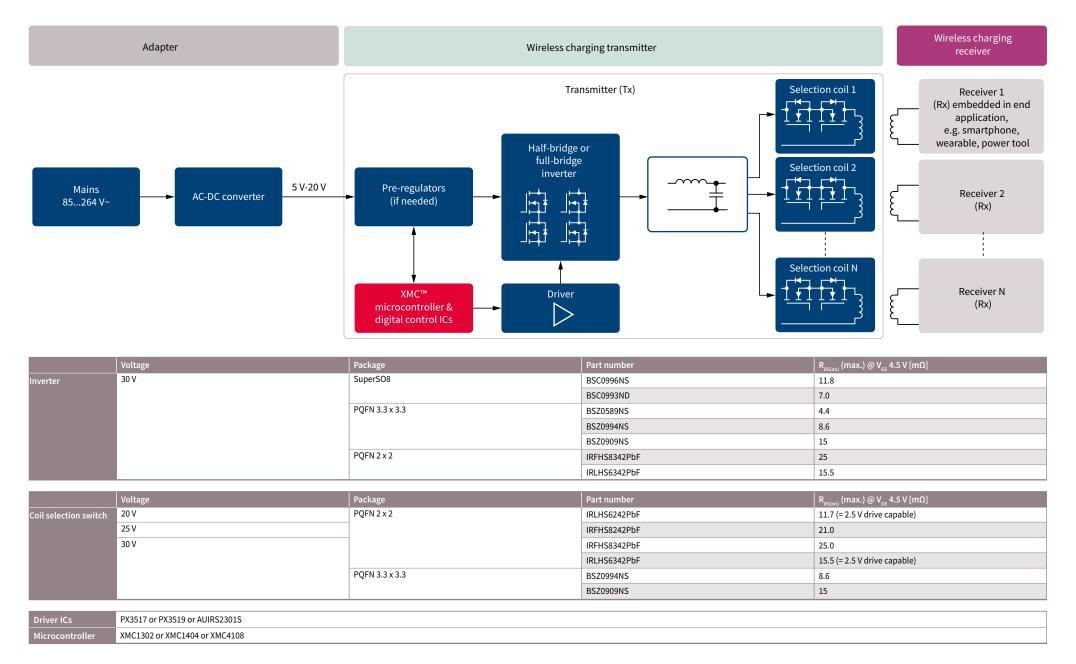
# Infineon offers products for the transmitter and adapter to charge various receiver applications





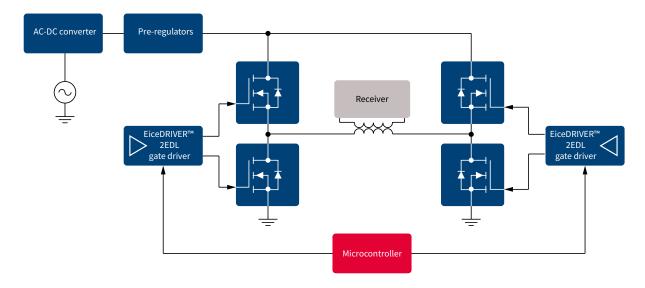


## Infineon offerings for inductive solutions (Qi & inductive AirFuel)



## Infineon offerings for resonant solutions (Resonant AirFuel)

### Class D – full-bridge



#### Please note

Class D full-bridge topology shown here, products also suitable for class D half-bridge topology

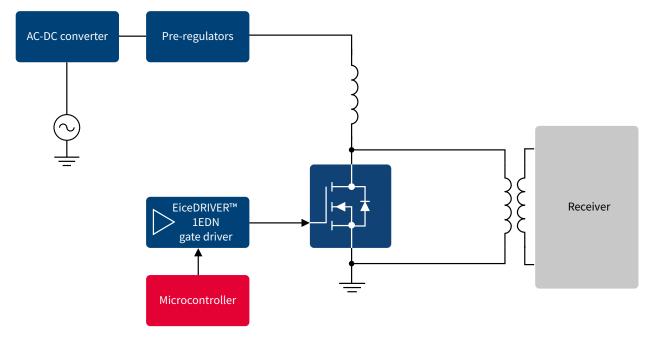
	Voltage class	Package	Part number	$R_{DS(on)}$ (max.) @ $V_{GS}$ 4.5 $V$ [m $\Omega$ ]	Q <sub>g</sub> typical	C <sub>oss</sub> typical	Topology
Inverter	30 V	PQFN 2 x 2 Dual	IRLHS6376PbF	48.0	2.8	32	Class D
		PQFN 3.3 x 3.3 Dual	BSZ0909ND	18.5	2.0	~120	Class D
		SOT-23	IRLML0030PbF	33	2.75	84	Class D
	40 V	SOT-23	IRLML0040PbF	62	2.8	49	Class D
	60 V		IRLML0060PbF	98	2.6	37	Class D
	80 V	PQFN 2 x 2	IRL80HS120	32.0	3.5	68	Class D/E
	100 V		IRL100HS121	42.0	2.7	62	Class D/E

Driver ICs	EiceDRIVER™ 2EDL71*			
	EiceDRIVER™ 1EDN			
Microcontroller	XMC1302 or XMC1404 or XMC4108			

<sup>\*</sup> coming soon

## Infineon offerings for resonant solutions (Resonant AirFuel)

### Class E – single-ended



#### Please note:

Class E single-ended topology shown here, products also suitable for class E differential topology

	Voltage	Package	Part number	$R_{DS(on)}$ (max.) @ $V_{GS}$ 4.5 $V$ [m $\Omega$ ]	Q <sub>e</sub> typical	C <sub>oss</sub> typical	Topology
Inverter MOSFETs	80 V	PQFN 2 x 2	IRL80HS120	32.0	3.5	68	Class D/E
	100 V		IRL100HS121	42.0	2.7	62	Class D/E
	150 V	PQFN 3.3 x 3.3	BSZ900N15NS3	75*	4.1*	46	Class E
			BSZ520N15NS3	42*	7.2*	80	Class E
	200 V		BSZ900N20NS3	78*	7.2*	52	Class E
			BSZ22DN20NS3	200*	3.5*	24	Class E
			BSZ12DN20NS3	111*	5.4*	39	Class E
	250 V		BSZ42DN25NS3	375*	3.6*	21	Class E

Driver ICs	EiceDRIVER™ 2EDL71**			
	EiceDRIVER™ 1EDN			
Microcontroller	XMC1302 or XMC1404 or XMC4108			

<sup>\* @</sup>V<sub>GS</sub> = 8 V

<sup>\*\*</sup> coming soon

### Highlight products for wireless charging



BSZ0909ND Half-bridge handles PQFN 3.3 x 3.3 package

Order now



**EiceDRIVER™ 2EDL71**Fast switching logic level half-bridge driver

Coming soon



IRL60/80/100
IR MOSFET™ PQFN 2 x 2
for half-bridge and
full-bridge topologies

Order now



**EiceDRIVER™ 1EDN**Rugged, cool and fast 1-channel low-side 4/8 A gate driver ICs

Order now

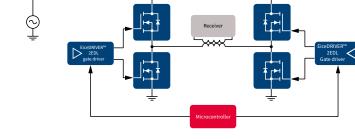
### Wireless charging selection tool

Application Power range Standard Topology Solution

#### This is our Infineon solution.

Please hover over each block with your mouse to see the recommended products.





Check out the wireless charging selection tool **now!** 



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